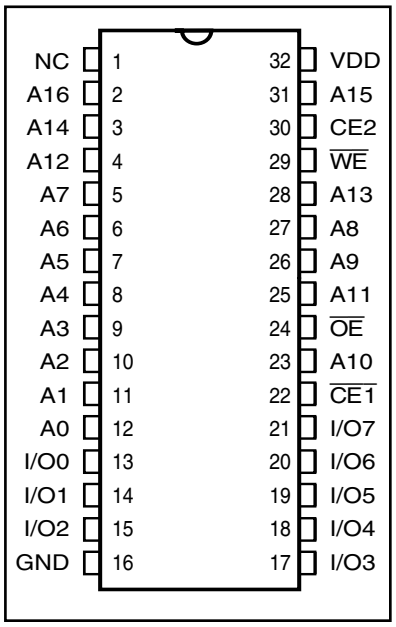
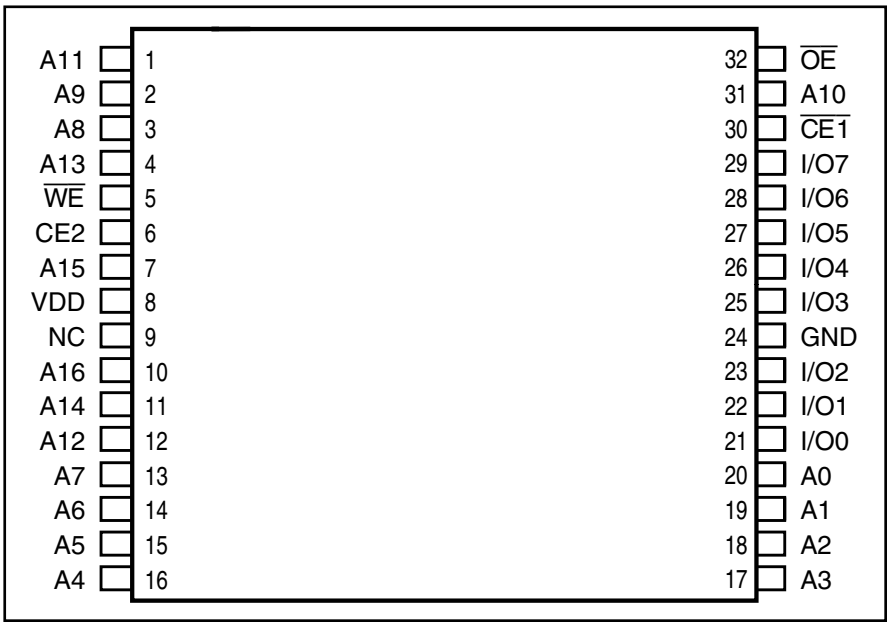
PIN CONFIGURATION
32-Pin SOJ



PIN CONFIGURATION
32-Pin TSOP (Type 1) (T) and sTSOP (Type 1) (H)



PIN DESCRIPTIONS

A0-A16	Address Inputs
$\overline{CE1}$	Chip Enable 1 Input
CE2	Chip Enable 2 Input
$\overline{OE}$	Output Enable Input
$\overline{WE}$	Write Enable Input
I/O0-I/O7	Input/Output
V_{DD}	Power
GND	Ground

OPERATING RANGE (IS61C1024AL)

Range	Ambient Temperature	V_{DD}
Commercial	0°C to +70°C	5V ± 10%
Industrial	-40°C to +85°C	5V ± 10%

OPERATING RANGE (IS64C1024AL)

Range	Ambient Temperature	V_{DD}
Automotive	-40°C to +125°C	5V ± 10%

TRUTH TABLE

Mode	$\overline{WE}$	$\overline{CE1}$	CE2	$\overline{OE}$	I/O Operation	V_{DD} Current
Not Selected	X	H	X	X	High-Z	I_{SB1}, I_{SB2}
(Power-down)	X	X	L	X	High-Z	I_{SB1}, I_{SB2}
Output Disabled	H	L	H	H	High-Z	I_{CC1}, I_{CC2}
Read	H	L	H	L	D_{OUT}	I_{CC1}, I_{CC2}
Write	L	L	H	X	D_{IN}	I_{CC1}, I_{CC2}

ABSOLUTE MAXIMUM RATINGS[1]

Symbol	Parameter	Value	Unit
V_{TERM}	Terminal Voltage with Respect to GND	–0.5 to +7.0	V
T_{STG}	Storage Temperature	–65 to +150	°C
P_T	Power Dissipation	1.5	W
I_{OUT}	DC Output Current (LOW)	20	mA

Notes:
1. Stress greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE[1,2]

Symbol	Parameter	Conditions	Max.	Unit
C_{IN}	Input Capacitance	V_{IN} = 0V	5	pF
C_{OUT}	Output Capacitance	V_{OUT} = 0V	7	pF

Notes:
1. Tested initially and after any design or process changes that may affect these parameters.
2. Test conditions: T_A = 25°C, f = 1 MHz, V_{DD} = 5.0V.

DC ELECTRICAL CHARACTERISTICS (Over Operating Range)

Symbol	Parameter	Test Conditions		Min.	Max.	Unit
V_{OH}	Output HIGH Voltage	V_{DD} = Min., I_{OH} = –4.0 mA		2.4	—	V
V_{OL}	Output LOW Voltage	V_{DD} = Min., I_{OL} = 8.0 mA		—	0.4	V
V_{IH}	Input HIGH Voltage			2.2	V_{DD} + 0.5	V
V_{IL}	Input LOW Voltage[1]			–0.3	0.8	V
I_{LI}	Input Leakage	GND ≤ V_{IN} ≤ V_{DD}	Com.	–1	1	µA
			Ind.	–2	2	
			Auto.	–5	5	
I_{LO}	Output Leakage	GND ≤ V_{OUT} ≤ V_{DD}	Com.	–1	1	µA
		Outputs Disabled	Ind.	–2	2	
			Auto.	–5	5	

Note:
1. V_{IL} = –3.0V for pulse width less than 10 ns.

IS61C1024AL/IS64C1024AL POWER SUPPLY CHARACTERISTICS[1] (Over Operating Range)

Symbol	Parameter	Test Conditions		-12 ns Min.	-12 ns Max.	-15 ns Min.	-15 ns Max.	Unit
I_{CC1}	V_{DD} Operating Supply Current	$V_{DD} = V_{DD\ MAX.}$, $\overline{CE1} = V_{IL}$ I_{OUT} = 0 mA, f = 0	Com. Ind. Auto.	— —	35 40	— —	45	mA
I_{CC2}	V_{DD} Dynamic Operating Supply Current	$V_{DD} = V_{DD\ MAX.}$, $\overline{CE1} = V_{IL}$ I_{OUT} = 0 mA, f = f_{MAX}	Com. Ind. Auto. typ.[2]	— — —	45 50 32	— —	55	mA
I_{SB1}	TTL Standby Current (TTL Inputs)	$V_{DD} = V_{DD\ MAX.}$, $V_{IN} = V_{IH}$ or V_{IL} $\overline{CE1} \geq V_{IH}$, f = 0 or CE2 $\leq V_{IL}$, f = 0	Com. Ind. Auto.	— —	1 1.5	— —	2	mA
I_{SB2}	CMOS Standby Current (CMOS Inputs)	$V_{DD} = V_{DD\ MAX.}$, $\overline{CE1} \geq V_{DD} - 0.2V$, CE2 $\leq 0.2V$ $V_{IN} \geq V_{DD} - 0.2V$, or $V_{IN} \leq 0.2V$, f = 0	Com. Ind. Auto. typ.[2]	— — —	400 450 200	— —	500	µA

Note:
1. At f = f_{MAX}, address and data inputs are cycling at the maximum frequency, f = 0 means no input lines change.
2. Typical Values are measured at V_{DD} = 5V, T_A = 25°C and not 100% tested.

READ CYCLE SWITCHING CHARACTERISTICS[1] (Over Operating Range)

Symbol	Parameter	-12 Min.	-12 Max.	-15 Min.	-15 Max.	Unit
t_{RC}	Read Cycle Time	12	—	15	—	ns
t_{AA}	Address Access Time	—	12	—	15	ns
t_{OHA}	Output Hold Time	3	—	3	—	ns
t_{ACE1}	$\overline{CE1}$ Access Time	—	12	—	15	ns
t_{ACE2}	CE2 Access Time	—	12	—	15	ns
t_{DOE}	$\overline{OE}$ Access Time	—	6	—	7	ns
t_{LZOE}[2]	$\overline{OE}$ to Low-Z Output	0	—	0	—	ns
t_{HZOE}[2]	$\overline{OE}$ to High-Z Output	0	6	0	6	ns
t_{LZCE1}[2]	$\overline{CE1}$ to Low-Z Output	2	—	2	—	ns
t_{LZCE2}[2]	CE2 to Low-Z Output	2	—	2	—	ns
t_{HZCE}[2]	$\overline{CE1}$ or CE2 to High-Z Output	0	7	0	8	ns
t_{PU}[3]	$\overline{CE1}$ or CE2 to Power-Up	0	—	0	—	ns
t_{PD}[3]	$\overline{CE1}$ or CE2 to Power-Down	—	12	—	12	ns

Notes:
1. Test conditions assume signal transition times of 3 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V and output loading specified in Figure 1.
2. Tested with the load in Figure 2. Transition is measured ±500 mV from steady-state voltage. Not 100% tested.
3. Not 100% tested.

AC TEST CONDITIONS

Parameter	Unit
Input Pulse Level	0V to 3.0V
Input Rise and Fall Times	3 ns
Input and Output Timing and Reference Level	1.5V
Output Load	See Figures 1 and 2

AC TEST LOADS

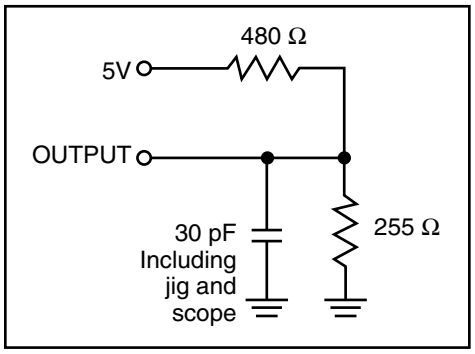


Figure 1

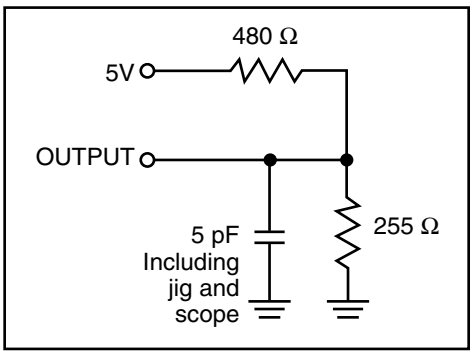
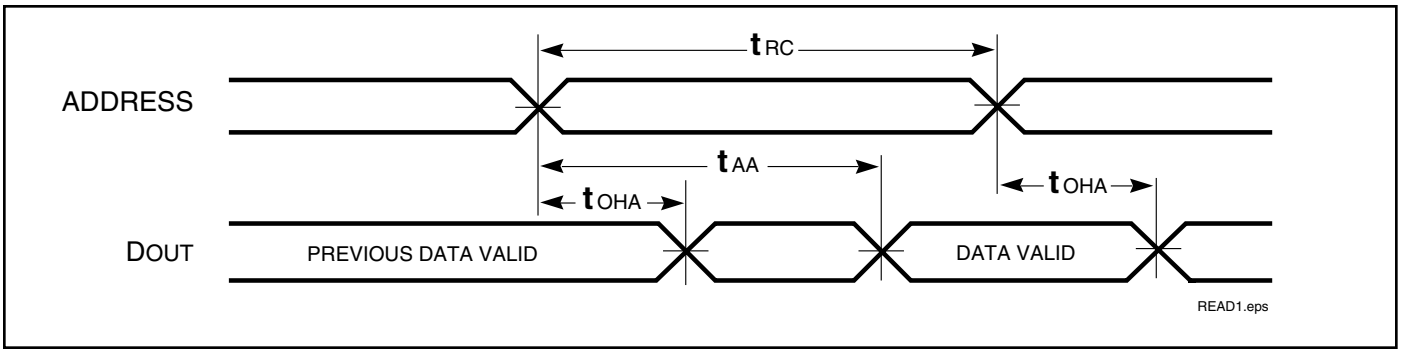


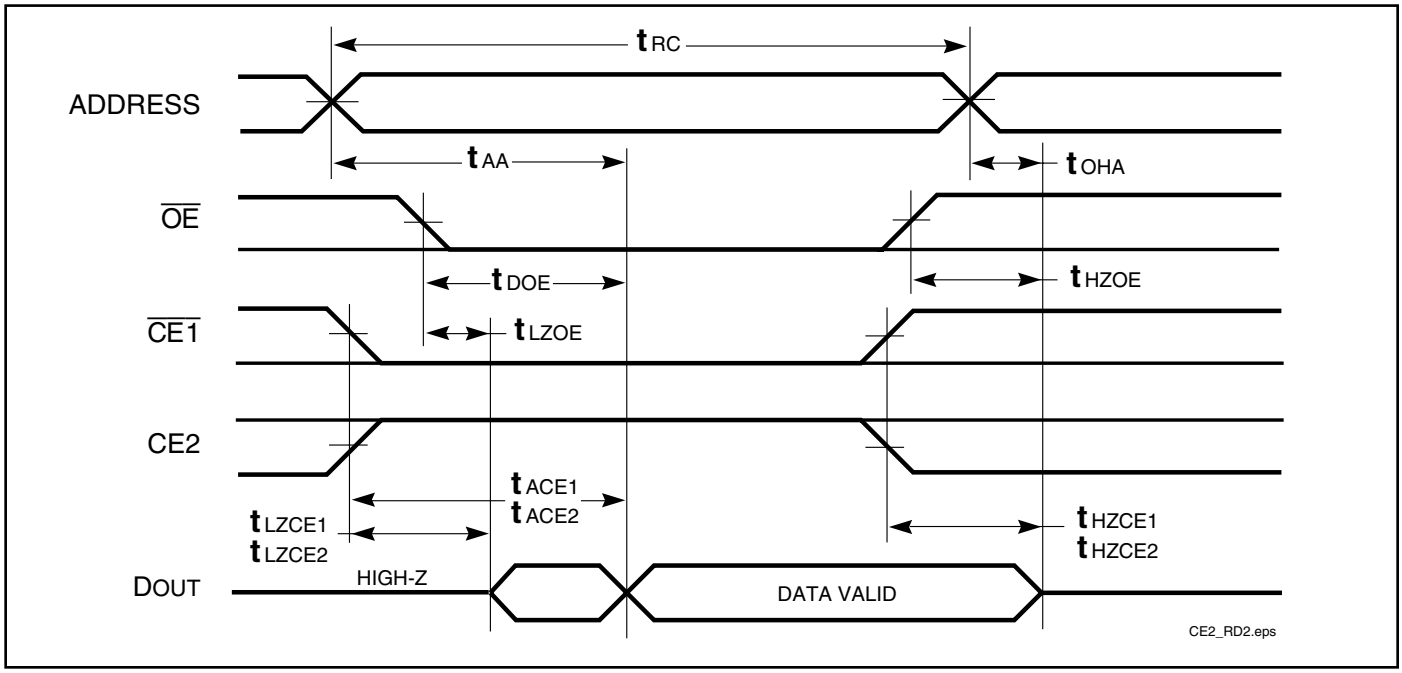
Figure 2

AC WAVEFORMS

READ CYCLE NO. 1[1,2]



READ CYCLE NO. 2[1,3]



Notes:
1. $\overline{WE}$ is HIGH for a Read Cycle.
2. The device is continuously selected. $\overline{OE}$, $\overline{CE1}$ = V_{IL}, CE2 = V_{IH}.
3. Address is valid prior to or coincident with $\overline{CE1}$ LOW and CE2 HIGH transitions.

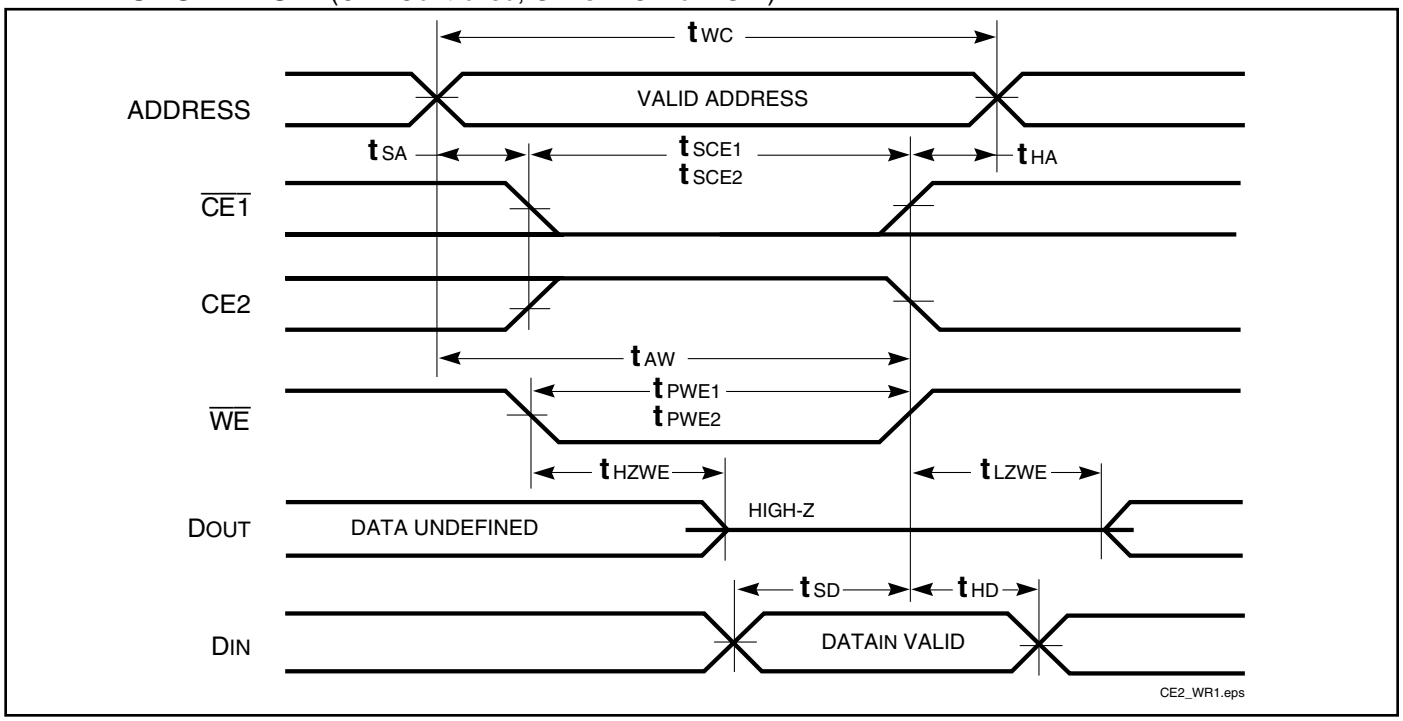
WRITE CYCLE SWITCHING CHARACTERISTICS[1,2] (Over Operating Range, Standard and Low Power)

Symbol	Parameter	-12 ns Min.	-12 ns Max.	-15 ns Min.	-15 ns Max.	Unit
t_{WC}	Write Cycle Time	12	—	15	—	ns
t_{SCE1}	$\overline{CE1}$ to Write End	10	—	12	—	ns
t_{SCE2}	CE2 to Write End	10	—	12	—	ns
t_{AW}	Address Setup Time to Write End	10	—	12	—	ns
t_{HA}	Address Hold from Write End	0	—	0	—	ns
t_{SA}	Address Setup Time	0	—	0	—	ns
t_{PWE}[3]	$\overline{WE}$ Pulse Width	10	—	12	—	ns
t_{SD}	Data Setup to Write End	7	—	10	—	ns
t_{HD}	Data Hold from Write End	0	—	0	—	ns
t_{HZWE}[4]	$\overline{WE}$ LOW to High-Z Output	—	7	—	7	ns
t_{LZWE}[4]	$\overline{WE}$ HIGH to Low-Z Output	2	—	2	—	ns

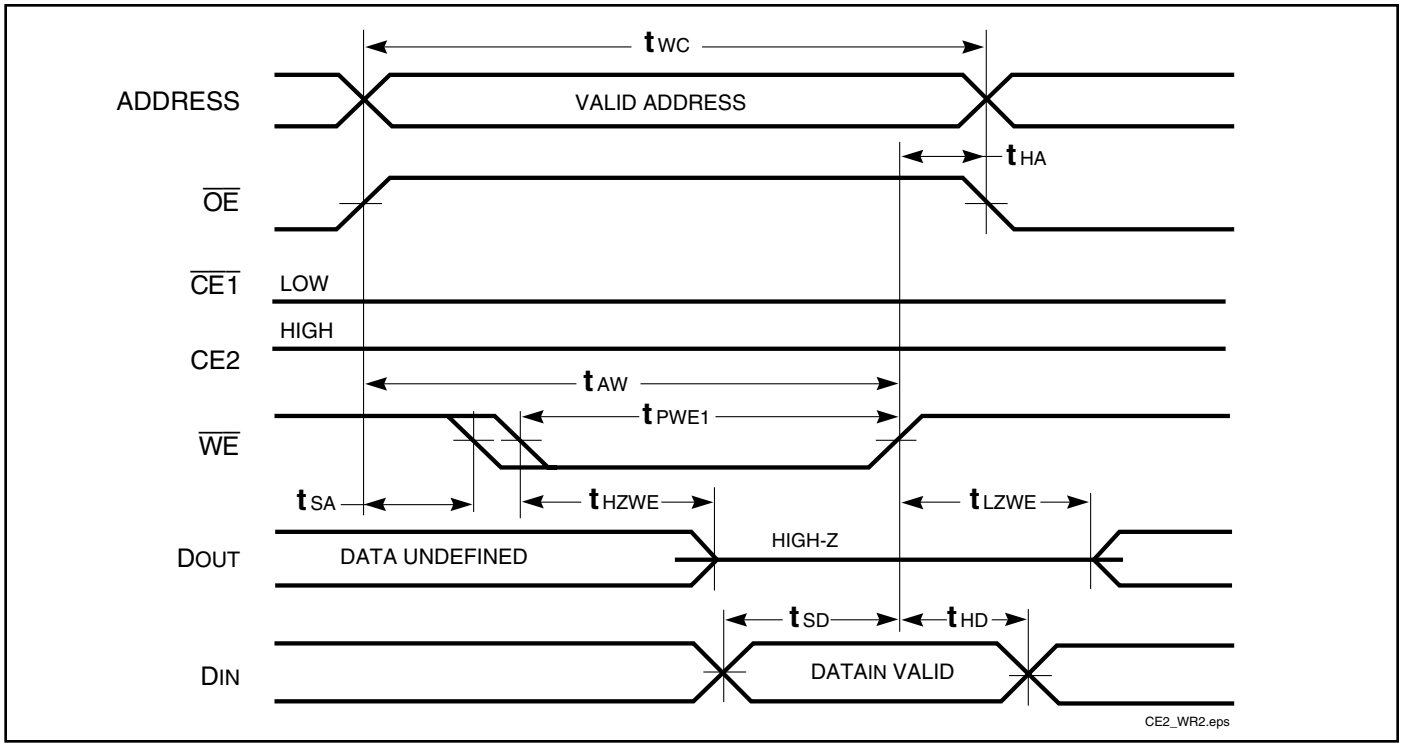
Notes:
1. Test conditions assume signal transition times of 5 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V and output loading specified in Figure 1.
2. The internal write time is defined by the overlap of $\overline{CE1}$ LOW, CE2 HIGH and $\overline{WE}$ LOW. All signals must be in valid states to initiate a Write, but any one can go inactive to terminate the Write. The Data Input Setup and Hold timing are referenced to the rising or falling edge of the signal that terminates the Write.
3. Tested with $\overline{OE}$ HIGH.
4. Tested with the load in Figure 2. Transition is measured ±500 mV from steady-state voltage. Not 100% tested.

AC WAVEFORMS

WRITE CYCLE NO. 1 ($\overline{CE1}$ Controlled, $\overline{OE}$ is HIGH or LOW) (1)



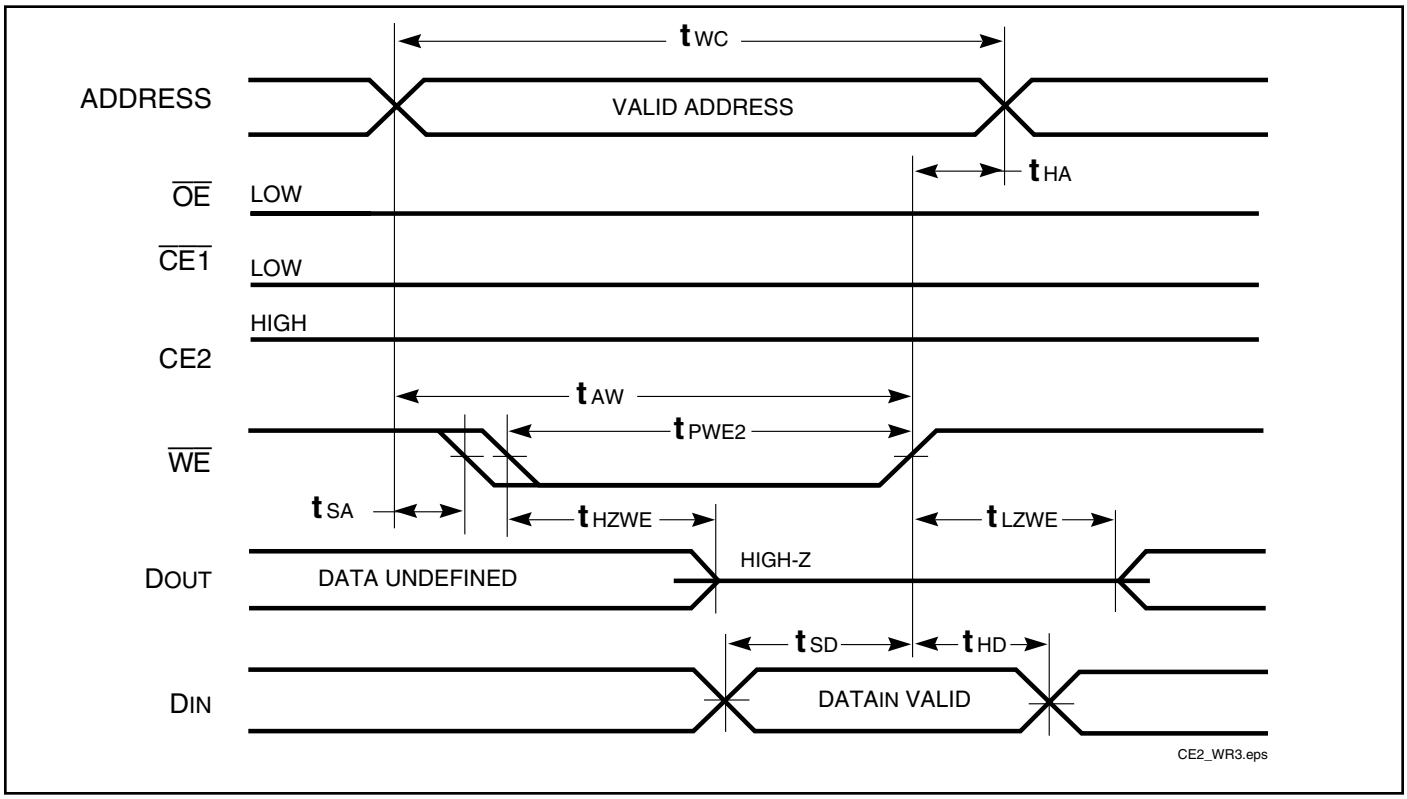
WRITE CYCLE NO. 2 ($\overline{OE}$ is HIGH During Write Cycle) (1,2)



Notes:

1. The internal write time is defined by the overlap of $\overline{CE1}$ LOW, CE2 HIGH and $\overline{WE}$ LOW. All signals must be in valid states to initiate a Write, but any one can go inactive to terminate the Write. The Data Input Setup and Hold timing are referenced to the rising or falling edge of the signal that terminates the Write.
2. I/O will assume the High-Z state if $\overline{OE}$ = V_{IH}.

WRITE CYCLE NO. 3 ($\overline{OE}$ is LOW During Write Cycle) [1]



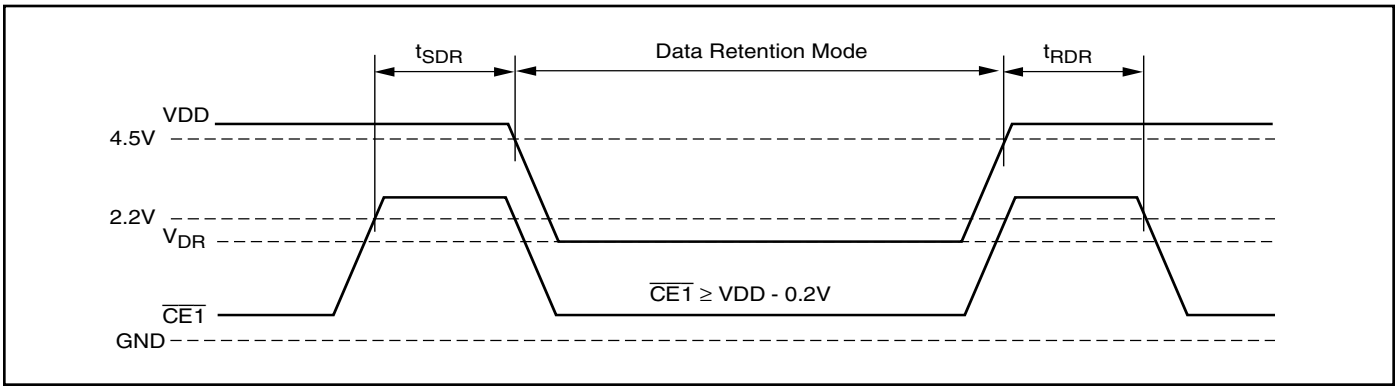
DATA RETENTION SWITCHING CHARACTERISTICS

Symbol	Parameter	Test Condition		Min.	Typ.(1)	Max.	Unit
V_{DR}	V_{DD} for Data Retention	See Data Retention Waveform		2.0		5.5	V
I_{DR}	Data Retention Current	V_{DD} = 2.0V, $\overline{CE1} \geq V_{DD} - 0.2V$	Com.	—	200	400	µA
		or CE2 ≤ 0.2V	Ind.	—	—	450	
		$V_{IN} \geq V_{DD} - 0.2V$, or $V_{IN} \leq V_{SS} + 0.2V$	Auto.	—	—	500	
t_{SDR}	Data Retention Setup Time	See Data Retention Waveform		0		—	ns
t_{RDR}	Recovery Time	See Data Retention Waveform		t_{RC}		—	ns

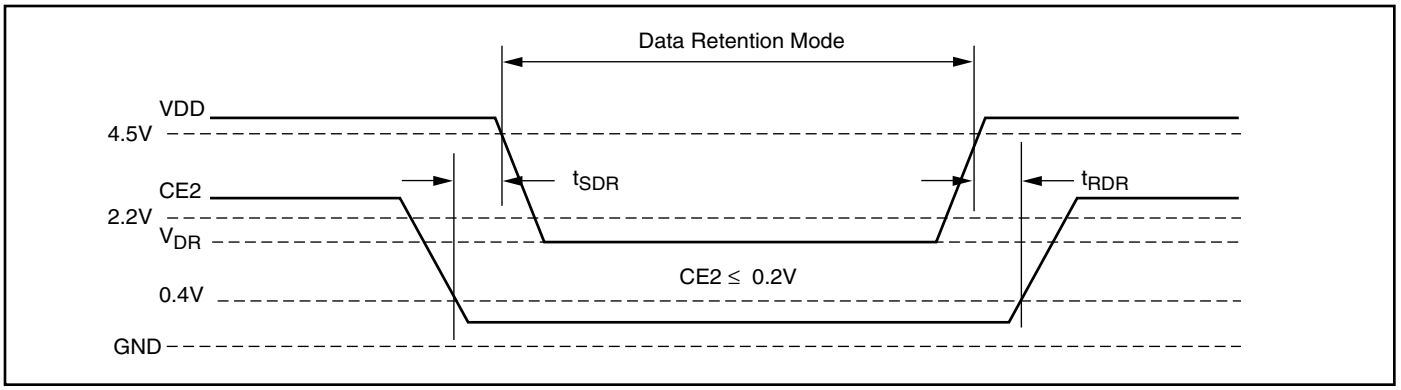
Note:

1. Typical Values are measured at V_{DD} = 5V, T_A = 25°C and not 100% tested.

DATA RETENTION WAVEFORM ($\overline{CE1}$ Controlled)



DATA RETENTION WAVEFORM (CE2 Controlled)



ORDERING INFORMATION: IS61C1024AL
Commercial Range: 0°C to +70°C

Speed (ns)	Order Part No.	Package
12	IS61C1024AL-12T	TSOP (Type I)

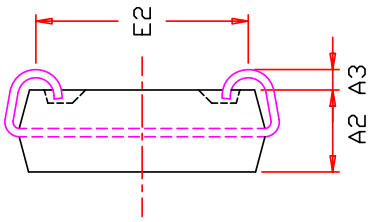
ORDERING INFORMATION: IS61C1024AL
Industrial Range: –40°C to +85°C

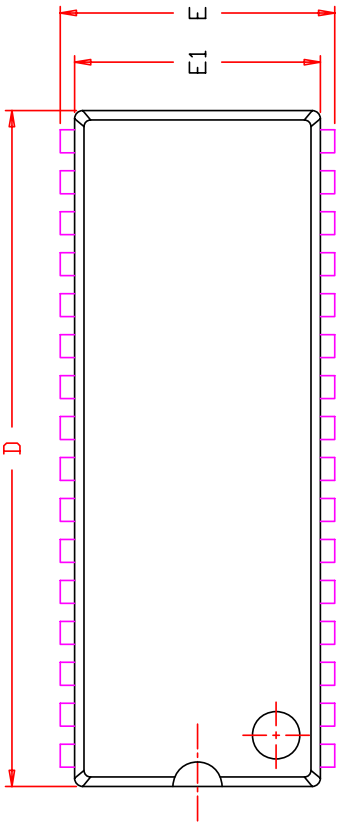
Speed (ns)	Order Part No.	Package
12	IS61C1024AL-12JLI	300-mil Plastic SOJ, Lead-free
	IS61C1024AL-12KI	400-mil Plastic SOJ
	IS61C1024AL-12KLI	400-mil Plastic SOJ, Lead-free
	IS61C1024AL-12HI	sTSOP (Type I)
	IS61C1024AL-12HLI	sTSOP (Type I), Lead-free
	IS61C1024AL-12TI	TSOP (Type I)
	IS61C1024AL-12TLI	TSOP (Type I), Lead-free

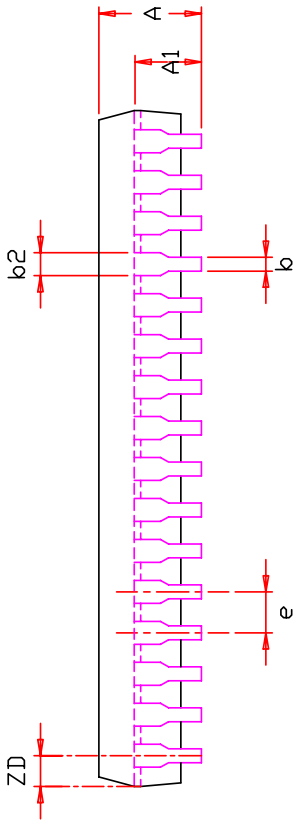
ORDERING INFORMATION: IS64C1024AL
Automotive Range: –40°C to +125°C

Speed (ns)	Order Part No.	Package
15	IS64C1024AL-15KA3	400-mil Plastic SOJ
	IS64C1024AL-15TA3	TSOP (Type I)

SYMBOL	DIMENSION IN MM			DIMENSION IN INCH		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	3.05	—	3.76	0.120	—	0.148
A1	2.08	—	2.41	0.082	—	0.095
A2	2.41	2.54	2.67	0.095	0.100	0.105
A3	0.64	—	1.09	0.025	—	0.043
b	0.41	—	0.51	0.016	—	0.020
b2	0.66	—	0.81	0.026	—	0.032
D	20.82	—	21.09	0.820	—	0.830
E	8.38	8.51	8.64	0.330	0.335	0.340
E1	7.49	7.62	7.75	0.295	0.300	0.305
E2	6.48	—	6.99	0.255	—	0.275
e	1.27 BSC,			0.050 BSC,		
ZD	0.95 REF.,			0.037 REF.,		





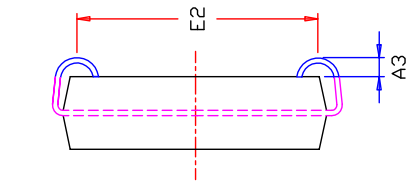


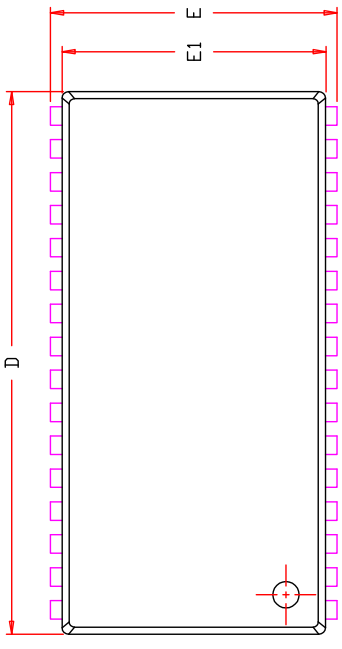
NOTE :

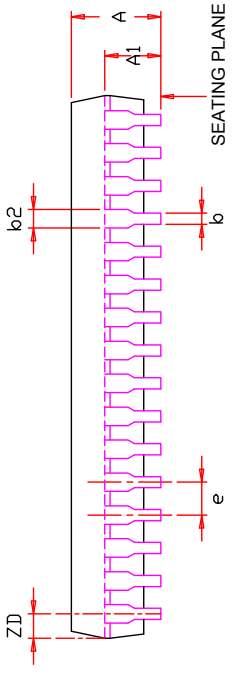
1. CONTROLLING DIMENSION : MM
2. DIMENSION D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
3. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION/INTRUSION.

TITLE	32L 300mil SOJ Package Outline	REV.	C	DATE	08/14/2009

SYMBOL	DIMENSION IN MM			DIMENSION IN INCH		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	3.25	—	3.76	0.128	—	0.148
A1	2.08	—	—	0.082	—	—
A3	0.635	—	—	0.025	—	—
b	0.38	—	0.51	0.015	—	0.020
b2	0.66	0.71	0.81	0.026	0.028	0.032
D	20.82	20.95	21.08	0.820	0.825	0.830
E	11.05	11.18	11.30	0.435	0.440	0.445
E1	10.03	10.16	10.29	0.395	0.400	0.405
E2	9.40 BSC			0.370 BSC		
e	1.27 BSC.			0.050 BSC.		
ZD	0.95 REF			0.037 REF		







NOTE :

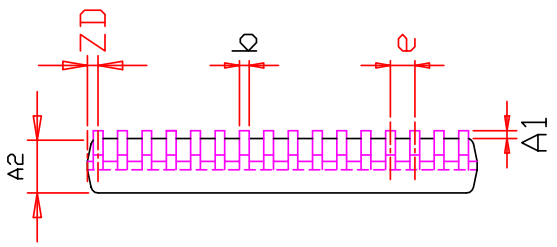
1. Controlling dimension : mm
2. Dimension D and E1 do not include mold protrusion .
3. Dimension b2 does not include dambar protrusion/intrusion.
4. Formed leads shall be planar with respect to one another within 0.1mm at the seating plane after final test.
5. Reference document : JEDEC SPEC MS-027.

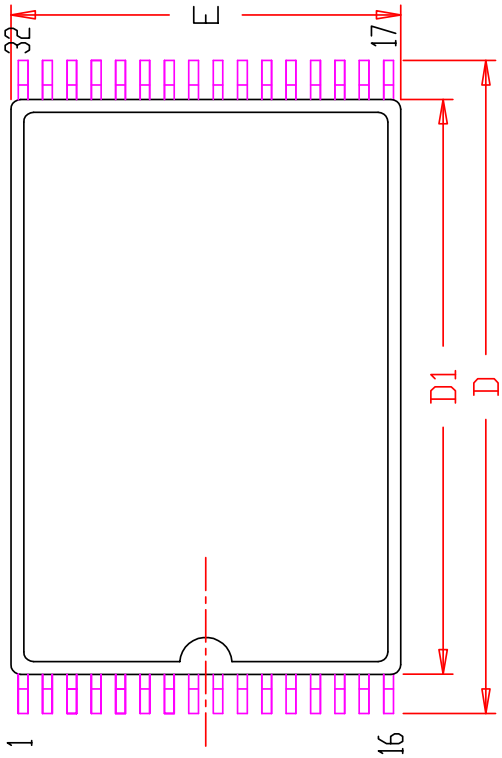
TITLE	32L 400mil SOJ Package Outline	REV.	E	DATE	12/19/2007

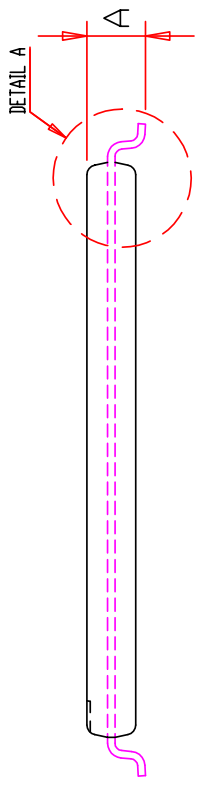
SYMBOL	DIMENSION IN MM			DIMENSION IN INCH		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.95	—	1.25	0.037	—	0.049
A1	0.05	—	0.15	0.002	—	0.008
A2	0.90	—	1.05	0.035	—	0.041
b	0.16	—	0.27	0.006	—	0.011
D	13.10	13.40	13.70	0.516	0.528	0.539
D1	11.70	11.80	11.90	0.461	0.465	0.469
E	7.90	8.00	8.10	0.311	0.315	0.319
e	0.50 BSC.			0.020 BSC.		
L	0.30	0.50	0.70	0.012	0.020	0.028
L1	0.25 BSC.			0.010 BSC.		
ZD	0.25 REF.			0.010 REF.		
Θ	0	3°	5°	0	3°	5°

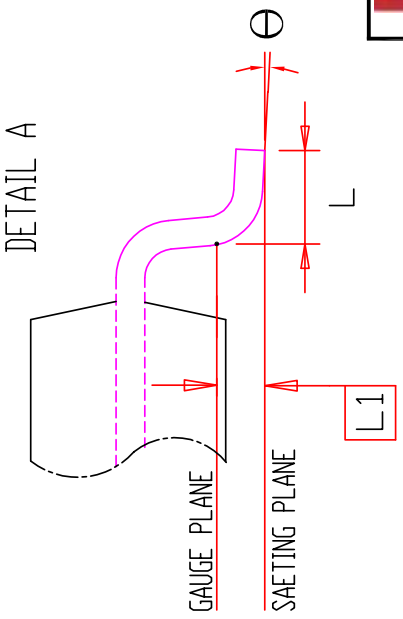
NOTE :

1. CONTROLLING DIMENSION : MM
2. DIMENSION D1 AND E DO NOT INCLUDE MOLD PROTRUSION.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION/INTRUSION.
4. Reference Document : JEDEC MO-183









TITLE	32L 8x13.4mm TSOP-1 Package Outline	REV.	E
		DATE	04/24/2009